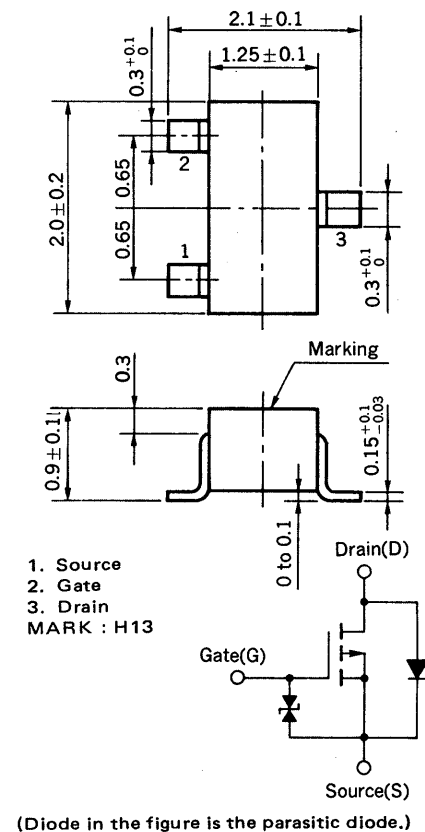


MOS FIELD EFFECT TRANSISTOR

2SJ202

P-CHANNEL MOS FET FOR SWITCHING

OUTLINE DIMENSIONS (Unit : mm)



The 2SJ202 is an P-channel vertical type MOS FET which can be driven by 2.5 V power supply.

As the MOS FET is driven by low voltage and does not require consideration of driving current, it is suitable for appliances including VTR cameras and headphone stereos which need power saving.

FEATURES

- Directly driven by ICs having a 3 V power supply.
- Not necessary to consider driving current because of its high input impedance.
- Possible to reduce the number of parts by omitting the bias resistor.
- Complementary to 2SK1580

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

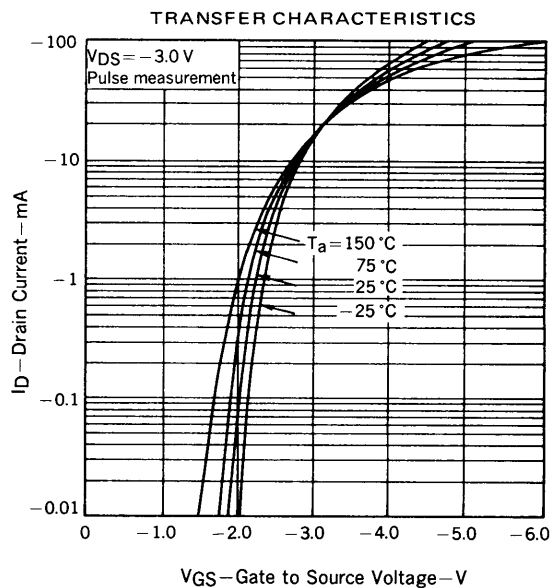
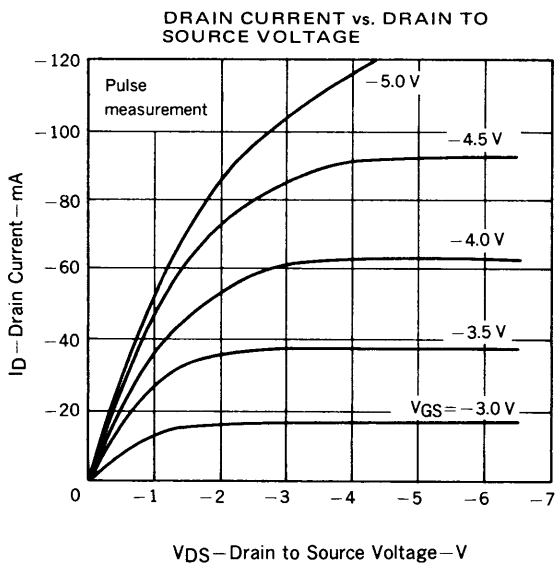
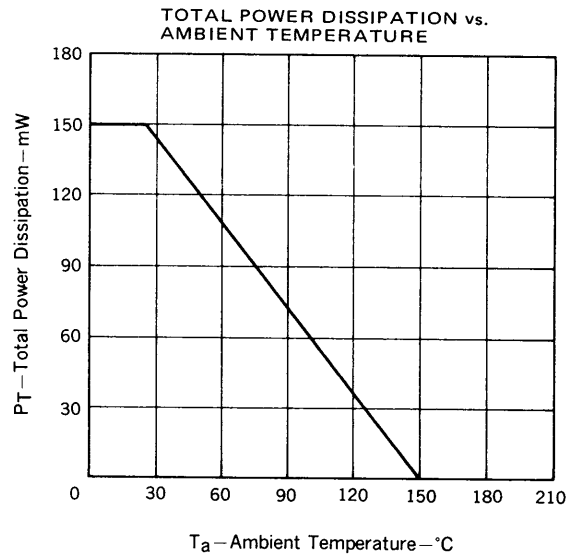
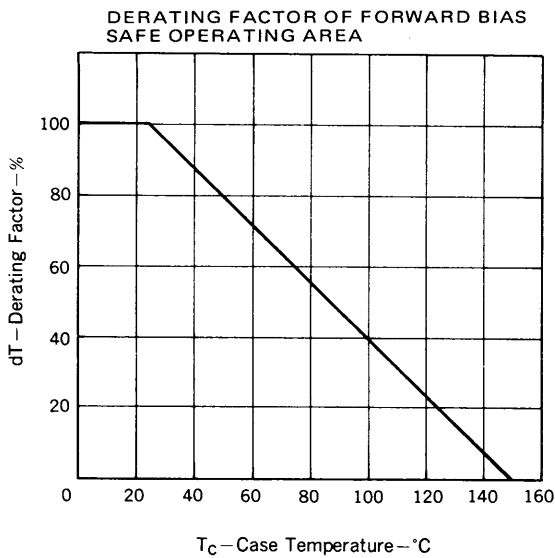
ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

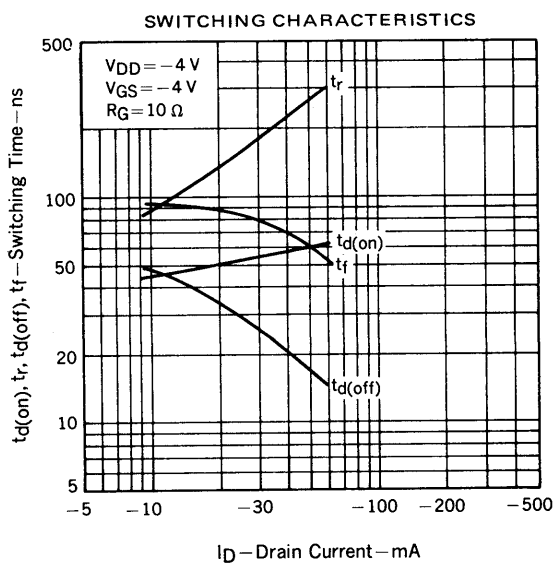
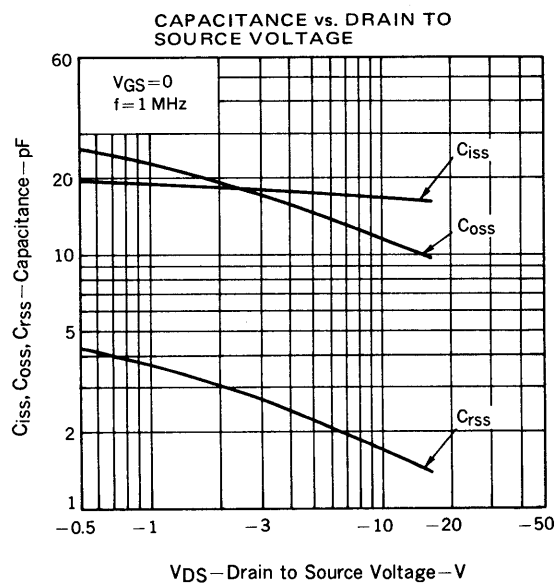
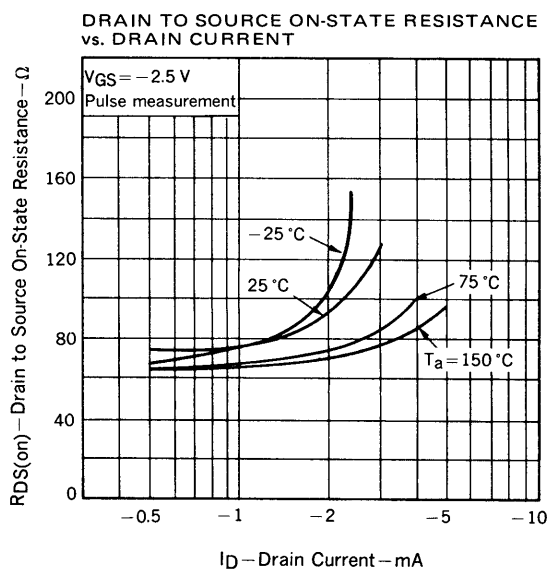
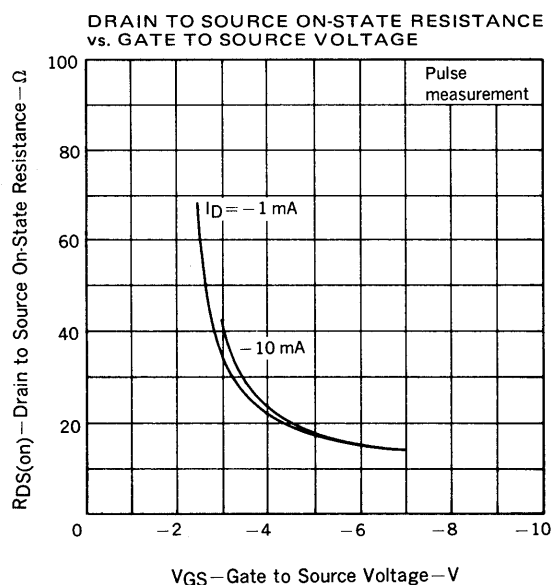
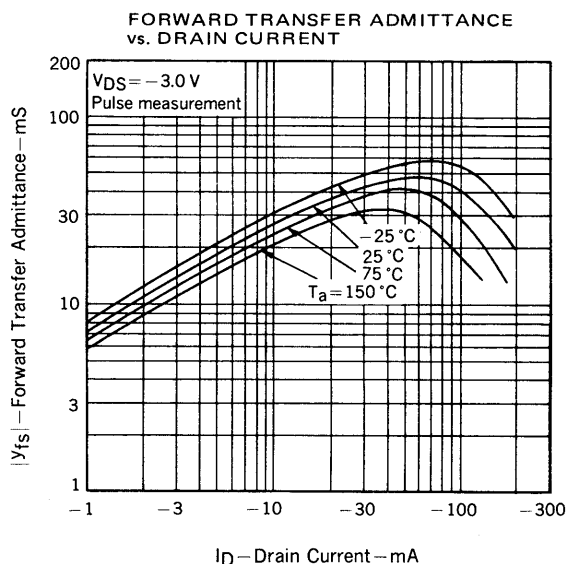
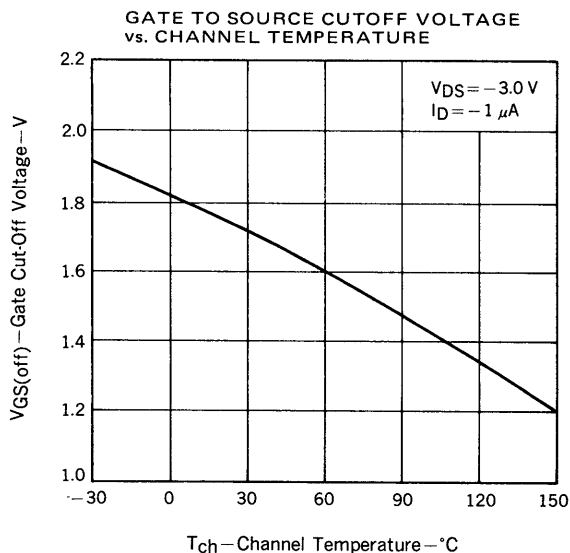
CHARACTERISTIC	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V_{DSS}	-16	V	$V_{GS} = 0$
Gate to Source Voltage	V_{GSS}	± 7	V	$V_{DS} = 0$
Drain Current	$I_D(\text{DC})$	± 100	mA	
Drain Current	$I_D(\text{pulse})$	± 200	mA	$PW \leq 10 \text{ ms}$, Duty Cycle $\leq 50 \%$
Total Power Dissipation	P_T	150	mW	
Channel Temperature	T_{ch}	150	$^\circ\text{C}$	
Operating Temperature	T_{opt}	-55 to +80	$^\circ\text{C}$	
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$	

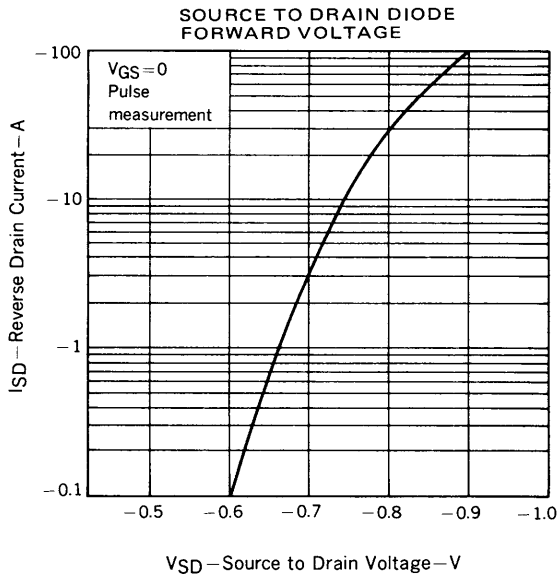
ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Drain Cut-off Current	I _{DSS}			-1.0	μA	V _{DS} = -16 V, V _{GS} = 0
Gate Leakage Current	I _{GSS}			±10	μA	V _{GS} = ±3.0 V, V _{DS} = 0
Gate Cut-off Voltage	V _{GS(off)}	-1.1	-1.7	-2.1	V	V _{DS} = -3.0 V, I _D = -1.0 μA
Forward Transfer Admittance	y _{fs}	20	27		mS	V _{DS} = -3.0 V, I _D = -10 mA
Drain to Source On-State Resistance	R _{DS(on)1}		70	100	Ω	V _{GS} = -2.5 V, I _D = -1.0 mA
Drain to Source On-State Resistance	R _{DS(on)2}		23	30	Ω	V _{GS} = -4.0 V, I _D = -1.0 mA
Input Capacitance	C _{iss}		18		pF	V _{DS} = -3 V, V _{GS} = 0, f = 1 MHz
Output Capacitance	C _{oss}		17		pF	
Feedback Capacitance	C _{rss}		3		pF	
Turn-On Delay Time	t _{d(on)}		40		ns	V _{GS(on)} = -4 V, R _G = 10 Ω, V _{DD} = -4 V, I _D = -1 mA, R _L = 4 kΩ
Rise Time	t _r		60		ns	
Turn-Off Delay Time	t _{d(off)}		60		ns	
Fall Time	t _f		100		ns	

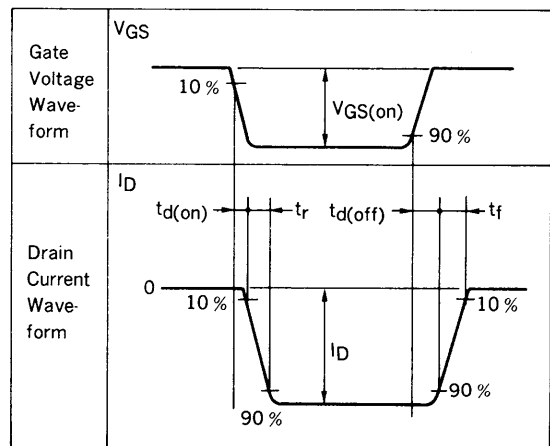
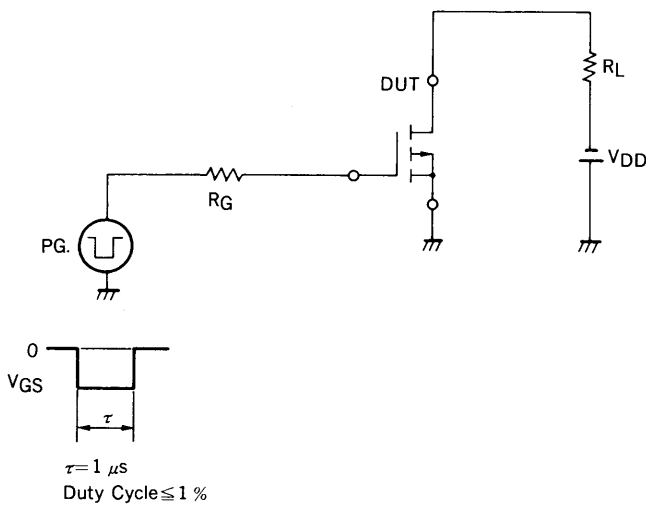
TYPICAL CHARACTERISTICS (T_a = 25 °C)







SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions.
Please consult with our representatives about soldering methods and conditions other than these recommended.

SURFACE MOUNT TYPE

For details of the recommended soldering conditions, see the information document.
"Device Mounting Manual for Surface Mounting (IEI-616)."

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions
Infrared Reflow	Package Peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00
Wave Soldering	Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none*	WS60-00

* Stored days under storage conditions at 25 °C and below 65 % R.H. after dry-pack opened.

Note 1: Combination of soldering methods should be avoided.

[MEMO]

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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those intended to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime systems etc.